TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED MESA TYPE

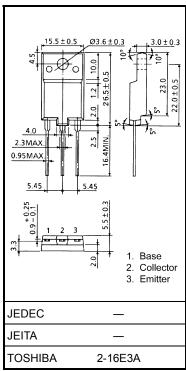
S2055N

COLOR TV HORIZONTAL OUTPUT APPLICATIONS

- High Voltage
- : VCES = 1500 V
- Low Saturation Voltage $: V_{CE} (sat) = 5 V (Max.)$
- High Speed
- ∶ t_f = 0.3µs (Typ.)
- Built-in Damper Type
- Collector Metal (Fin) is Fully Covered with Mold Resin.

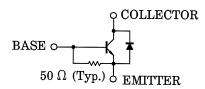
MAXIMUM RATINGS (Tc = 25°C)

CHARACTERISTICS		SYMBOL	RATING	UNIT	
Collector-Emitter Voltage		V _{CES}	1500	V	
Emitter-Base Voltage		V _{EBO}	5	V	
Collector Current	DC	Ι _C	8	А	
	Pulse	ICP	15	А	
Base Current		Ι _Β	4	А	
Collector Power Dissipation		P _C	50	W	
Junction Temperature		Тј	150	°C	
Storage Temperature Range		T _{stg}	-55~150	°C	
Thermal Resistance		R _{th (j−c)}	2.5	°C / W	

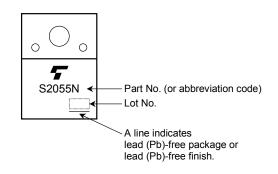


Weight: 5.5 g (typ.)

EQUIVALENT CIRCUIT



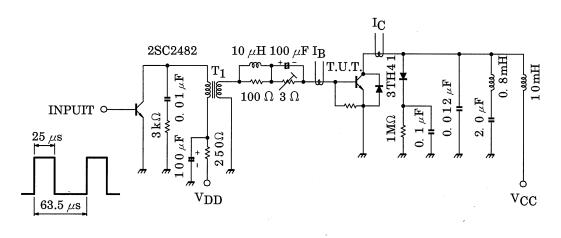
MARKING



Unit: mm

ELECTRICAL CHARACTERISTICS (Tc = 25°C)

CHARACTERISTICS		SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT	
Collector Cut-off Current		I _{CBO}	V _{CB} = 1500 V, V _{BE} = 0	—	— — 1 mA		mA	
Emitter-Base Breakdown Voltage		V (BR) EBO	I _E = 0.4 A, I _C = 0	5	_	_	— V	
DC Current Gain		h _{FE (1)}	V _{CE} = 5 V, I _C = 1 A	8	—	25		
		h _{FE (2)}	V _{CE} = 5 V, I _C = 4.5 A	4.5	_	9	_	
Collector-Emitter Saturation Voltage		V _{CE (sat)}	I _C = 4.5 A, I _B = 2 A	_	_	1	v	
			I _C = 4.5 A, I _B = 1 A	_	_	5		
Base-Emitter Saturation Voltage		V _{BE (sat)}	I _C = 4.5 A, I _B = 1 A	_	0.9	1.2	V	
Forwardn Voltage(Damper Diode)		V _F	I _F = 6 A	_	1.6	2.0	V	
Collector-Emitter Sustain Voltage		V _{CEX (sus)}	L = 40 mH, I _C = 0.5A V _{BE} = -1.7 V	700	_	_	V	
Transition Frequency		fT	V _{CE} = 10 V, I _C = 0.1 A	_	2	_	MHz	
Collector Output Capacitance		C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	95	—	pF	
Switching Time (Fig. 1)	Storage Time	t _{stg}	I _{CP} = 4.5 A, I _{B1 (end)} = 1 A f _H = 15.75 kHz	—	7.5	11	μs	
	Fall Time	t _f		_	0.3	0.6		



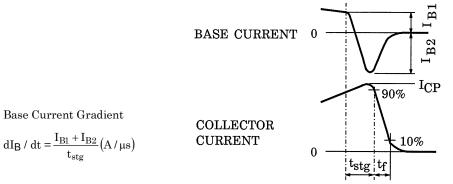
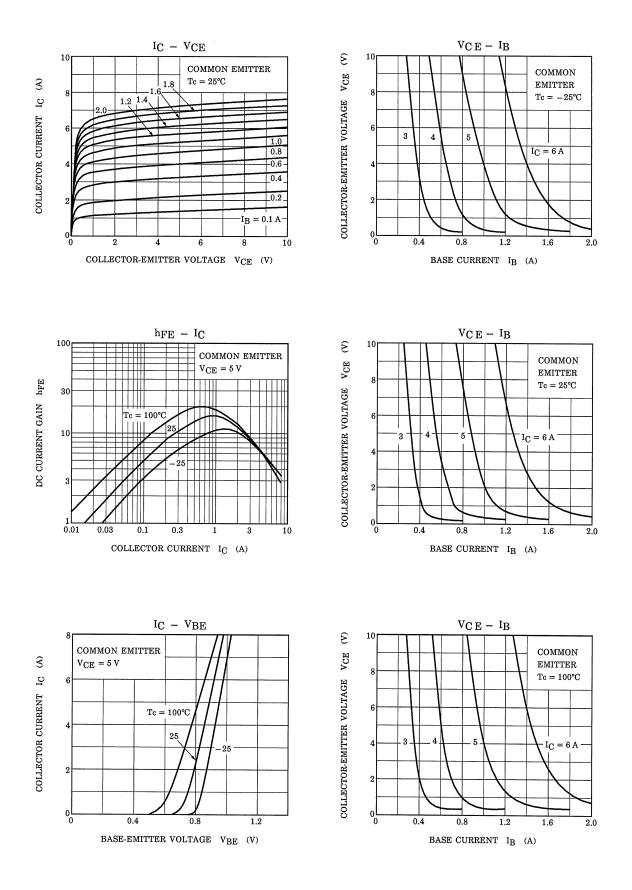
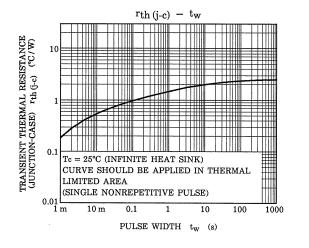


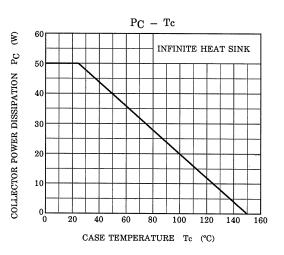
Fig. 1 SWITCHING TIME TEST CIRCUIT

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SAFE OPERATING AREA 50 -⁻I_C MAX. (PULSED) ※ [·] ++++++ 30 $10 \ \mu s \%$ IC MAX. (PULSED) 💥 $00 \ \mu s$ ms× 10 IC MAX. Ð 5 (CONTINUOUS) 0 ms ц 3 DC OPERATION COLLECTOR CURRENT $Tc = 25^{\circ}C$ 1 **100 ms** 0.5 0.3 X SINGLE 0.1 NONREPETITIVE PULSE $Tc = 25^{\circ}C$ 50 m CURVES MUST BE 30 m DERATED LINEARLY WITH INCREASE IN VCEX (SUS TEMPERATURE. MAX. 10 mL 1 3 10 30 100 300 1000 COLLECTOR-EMITTER VOLTAGE VCE (V)

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